

(1) IPD: Industrial & Power Discretes - ASD: Application Specific Device − IPAD™: Integrated Passive and Active Devices

Product/Process Change Notification

Additional Assembly and Test Location in China for Protection devices housed in

Additio	Additional Assembly and Test Location in Online for Trotection devices housed in						
SMA / SMB packages							
Notification number:	IPD-DIS/9053	Issue Date	03/02/2	2015			
Issued by	Aline AUGIS						
Product series a	affected by the change	The product series in	volved in this product	ion extension are listed	below.		
	anoctou by the change	SMB	SMB	SMA	SMA		
		unidirectionnel	bidirectionnel	unidirectionnel	bidirectionnel		
		SM6T15A	SM6T15CA	SMAJ12A-TR	SMAJ12CA-TR		
		SM6T18A	SM6T18CA	SMAJ13A-TR	SMAJ13CA-TR		
		SM6T22A	SM6T22CA	SMAJ15A-TR	SMAJ15CA-TR		
		SM6T24A	SM6T24CA	SMAJ18A-TR	SMAJ18CA-TR		
		SM6T27A	SM6T27CA	SMAJ20A-TR	SMAJ24CA-TR		
		SM6T30A	SM6T30CA	SMAJ24A-TR	SMAJ26CA-TR		
		SM6T33A	SM6T33CA	SMAJ26A-TR	SMAJ28CA-TR		
		SM6T36A	SM6T36CA	SMAJ28A-TR	SMAJ30CA-TR		
		SM6T39A	SM6T39CA	SMAJ30A-TR	SMAJ33CA-TR		
		SMBJ12A-TR	SM6T56CA	SMAJ33A-TR	SMAJ40CA-TR		
		SMBJ15A-TR	SM6T68CA		SMAJ43CA-TR		
		SMBJ16A-TR	SMBJ12CA-TR		SMAJ48CA-TR		
		SMBJ18A-TR	SMBJ13CA-TR		SMAJ58CA-TR		
		SMBJ20A-TR	SMBJ15CA-TR		SMAJ70CA-TR		
		SMBJ22A-TR	SMBJ18CA-TR				
		SMBJ24A-TR	SMBJ20CA-TR				
		SMBJ26A-TR	SMBJ22CA-TR				
		SMBJ28A-TR SMBJ30A-TR	SMBJ24CA-TR SMBJ26CA-TR				
		SMBJ33A-TR	SMBJ28CA-TR				
		J2000	SMBJ30CA-TR				
			SMBJ33CA-TR				
			SMBJ36CA-TR				
			SMBJ40CA-TR				
			SMBJ48CA-TR				

Type of change

Assembly site multisourcing

Description of the change

In order to better meet the market demand, we have decided to expand our manufacturing capacities for all our Protection devices housed in SMA / SMB package with one additional assembly and test line in a new China subcontractor.

SMBJ58CA-TR SMBJ70CA-TR

Multi- sourcing	Package	Current	New
Assembly & test location	SMA / SMB	CHINA (subco 1) – ECOPACK®2 MOROCCO (ST plant) – ECOPACK®2	CHINA (subco 1) – ECOPACK®2 MOROCCO (ST plant) – ECOPACK®2 CHINA (subco 2) – ECOPACK®2

Specific devices not expressly listed in the above table are included in this change.

Issue date 03-02-2015 1/2

STMicroelectronics IPD - ASD & IPAD™ Division¹ BU Protection



(1) IPD: Industrial & Power Discretes - ASD: Application Specific Device - IPAD™: Integrated Passive and Active Devices

Reason for change

This multi-sourcing will increase our **manufacturing capacity** for a better service on the considered **Protection devices** housed in the **SMA / SMB** package.

Former versus changed product:

The changed products do not present modified electrical, dimensional or thermal parameters, leaving unchanged the current information published in the product datasheet

The Moisture Sensitivity Level of the part (according to the IPC/JEDEC JSTD-020D standard) remains unchanged.

The footprint recommended by ST remains the same.

There is no change in the packing modes and the standard delivery quantities either.

The products remain in full compliance with the ST ECOPACK®2 grade ("halogen-free").

Disposition of former products

Deliveries of former product will continue.

Marking and traceability

Traceability for the implemented change will be ensured by the **marking**, an **internal codification** and by the **Q.A. number**.

Package	Marking
MOROCCO (ST plant)	CZ
CHINA (subco 1)	GP
CHINA (subco 2)	G3

Qualification complete date

22-05-2014

Forecasted sample availability

Samples are available upon request.

Change implementation schedule

Sales types	Estimated production start	Estimated first shipments
All	W22-2014	W19-2015

Comments:

Customer's feedback

Please contact your local ST sales representative or quality contact for requests concerning this change notification. Absence of acknowledgement of this PCN within 30 days of receipt will constitute acceptance of the change Absence of additional response within 90 days of receipt of this PCN will constitute acceptance of the change

Qualification program and results	QRP14107 Attached

Issue date 03-02-2015 2/2



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Reliability Report

Additional Assembly and Test Location in China for protection devices in SMA / SMB packages

	G	eneral Inforr	nation	
Product Line	Protection / T			
P/N	SMB UNI SM6T15A SM6T15A SM6T18A SM6T22A SM6T24A SM6T27A SM6T30A SM6T30A SM6T30A SM6T36A SM6T36A SM6T36A SM6T36A SMBJ12A-TR SMBJ15A-TR SMBJ16A-TR SMBJ20A-TR SMBJ26A-TR SMBJ36A-TR SMBJ36A-TR SMBJ36A-TR	SMB BI SM6T15CA SM6T18CA SM6T2CA SM6T24CA SM6T27CA SM6T30CA SM6T36CA SM6T36CA SM6T36CA SM6T36CA SM6T36CA SM6T36CA SM6T6CA SM6T6CA SM6T6CA SM6T6CA SMBJ12CA-TR SMBJ12CA-TR SMBJ12CA-TR SMBJ2CA-TR SMBJ2CA-TR SMBJ2CA-TR SMBJ2CA-TR SMBJ2CA-TR SMBJ2CA-TR SMBJ2CA-TR SMBJ26CA-TR SMBJ26CA-TR SMBJ26CA-TR	SMA UNI SMAJ12A-TR SMAJ13A-TR SMAJ15A-TR SMAJ15A-TR SMAJ20A-TR SMAJ20A-TR SMAJ24A-TR SMAJ28A-TR SMAJ28A-TR SMAJ33A-TR	SMA BI SMAJ12CA-TR SMAJ13CA-TR SMAJ15CA-TR SMAJ16CA-TR SMAJ2CA-TR SMAJ26CA-TR SMAJ26CA-TR SMAJ26CA-TR SMAJ30CA-TR SMAJ30CA-TR SMAJ30CA-TR SMAJ40CA-TR SMAJ40CA-TR SMAJ40CA-TR SMAJ40CA-TR SMAJ40CA-TR SMAJ40CA-TR
Product Group Product	IPG	SMBJ30CA-TR SMBJ36CA-TR SMBJ36CA-TR SMBJ40CA-TR SMBJ48CA-TR SMBJ58CA-TR SMBJ70CA-TR		
division Package Maturity level step	ASD&IPAD SMA / SMB Qualified			

	Locations
Wafer fab	ST TOURS (FRANCE)
Assembly plant	ST CHINA
Reliability Lab	ST TOURS (FRANCE)

DOCUMENT INFORMATION

Version	Date	Pages	Prepared by	Approved by	Comment
1.0	13/01/2015	7	J.MICHELON	J.P. REBRASSE	

Note: This report is a summary of the reliability trials performed in good faith by STMicroelectronics in order to evaluate the potential reliability risks during the product life using a set of defined test methods.

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1 APPLICABLE AND REFERENCE DOCUMENTS

Document reference	Short description
JESD47 Stress-Test-Driven Qualification of Integrated Circuits	
SOP 2614 Reliability requirements for product qualification	
0061692 Reliability tests and criteria for qualifications	
SOP 2610	general product qualification procedure
JESD 22	Reliability test methods for packaged devices

2 GLOSSARY

DUT	Device Under Test
PCB	Printed Circuit Board
SS	Sample Size
PC	Pre-conditionning Pre-conditionning
HTRB	High Temperature Reverse Bias
TC	Temperature Cycling
uHAST	Unbiased Highly Accelerated Stress Test
THB	Temperature Humidity Bias

3 OBJECTIVES

Reason for the change:

This multi-sourcing will increase our manufacturing capacity for a better service on the considered Protection devices housed in the SMA / SMB package.

4 CONCLUSION

Qualification Plan requirements have been fulfilled without exception. Reliability tests have shown that the devices behave correctly against environmental tests (no failure). Moreover, the stability of electrical parameters during the accelerated tests demonstrates the robustness of the products and safe operation, which is consequently expected during their lifetime.

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5 DEVICE CHARACTERISTICS

5.1 **Description of the change**

In order to better meet the market demand, we have decided to expand our manufacturing capacities for all our Protection devices housed in SMA / SMB package with one additional assembly and test line in a new China subcontractor.

Multi- sourcing	Package	Current	New
Assembly & test location	SMA / SMB	CHINA (subco 1) – ECOPACK®2 MOROCCO (ST plant) – ECOPACK®2	CHINA (subco 1) – ECOPACK®2 MOROCCO (ST plant) – ECOPACK®2 CHINA (subco 2) – ECOPACK®2

Specific devices not expressly listed in the above table are included in this change.

6 TESTS RESULTS SUMMARY

6.1 Test vehicle

Lot #	Commercial product	Wafer manufacturing plant	Assembly plant	Comments
Lot 1	SMAJ33CA			
Lot 2	SMAJ70CA			
Lot 3	SMBJ70CA	STMicroelectronics	CHINA subcon 2	Ouglification late
Lot 4	SMAJ12A	Tours (France)	CHINA SUDCON 2	Qualification lots
Lot 5	SMAJ33A			
Lot 6	SMBJ70A			





6.2 **Test plan and results summary**

					Failure/SS							
Test	РС	Std ref.	Conditions	ss	Steps	Lot 1	Lot 2	Lot 3	Lot 4	Lot 5	Lot 6	Note
Package Or	Package Oriented Tests											
			Ta = 85°C, RH = 85% Bias = VRM	100	168h	-	0/25	0/25	•	-	0/25	
THB	Υ	JESD22 A- 101			504h	-	0/25	0/25	-	-	0/25	
					1000h		0/25	0/25	-	-	0/25	
T0	, JESD22 A-	-65°C/+150°C	400	100C		0/25	0/25	-	-	0/25		
TC	Υ	104	2 cycles/hour	100	500C		0/25	0/25	-	-	0/25	
uHAST	Υ	JESD22 A- 102	T=130°C RH=85%, P=2.3 Bars	100	96h	-	0/25	0/25	-	-	0/25	
Repetitive surges	Υ	ADCS0060 282	Ipp _{max} datasheet	140	140	0/20	0/20	0/20	0/20	0/20	0/20	
Solderability	N	JESD22 B- 102	Dry ageing 16h SnPb bath and SnAgCu Wet ageing 8h SnPb bath and SnAgCu	60	Visual inspection	-	-	-	0/60	-	-	
Die Oriented Tests												
		JESD22 A- 108	Tj = 150°C, Bias = VRM		168h	0/77	0/77	0/77	0/77	0/77	-	
HTRB	N			385	504h	0/77	0/77	0/77	0/77	0/77	-	
					1000h	0/77	0/77	0/77	0/77	0/77	-	





6.3 **Tests Description**

Test name	Description	Purpose			
Die Oriented					
HTRB High Temperature Reverse Bias	The device is stressed in static configuration, trying to satisfy as much as possible the following conditions: low power dissipation; max. supply voltage compatible with diffusion process and internal circuitry limitations;	To determine the effects of bias conditions and temperature on solid state devices over time. It simulates the devices operating condition in an accelerated way. To maximize the electrical field across either reverse-biased junctions or dielectric layers, in order to investigate the failure modes linked to mobile contamination, oxide ageing, layout sensitivity to surface effects.			
Package Oriented					
uHAST Unbiased Highly Accelerated Stress Test	The device is stored without bias under 130°C 85% RH during 96 hours, or equivalent 110°C 85% RH during 264 hours.	The Unbiased HAST is performed for the purpose of evaluating the reliability of non-hermetic packaged solidstate devices in humid environments. It is a highly accelerated test which employs temperature and humidity under non-condensing conditions to accelerate the penetration of moisture through the external protective material (encapsulant or seal) or along the interface between the external protective material and the metallic conductors which pass through it. Bias is not applied in this test to ensure the failure mechanisms potentially overshadowed by bias can be uncovered (e.g. galvanic corrosion).			
PC Preconditioning	The device is submitted to a typical temperature profile used for surface mounting devices, after a controlled moisture absorption.	to verify that the surface mounting stress does			
THB Temperature Humidity Bias	The device is biased in static configuration minimizing its internal power dissipation, and stored at controlled conditions of ambient temperature and relative humidity.	To evaluate the package moisture resistance with electrical field applied, both electrolytic and galvanic corrosion are put in evidence.			



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Test name	Description	Purpose			
TC Temperature Cycling	The device is submitted to cycled temperature excursions, between a hot and a cold chamber in air atmosphere.	To investigate failure modes related to the thermo-mechanical stress induced by the different thermal expansion of the materials interacting in the die-package system. Typical failure modes are linked to metal displacement, dielectric cracking, molding compound delamination, wire-bonds failure, die-attach layer degradation.			
Solderability	The purpose of this test method is to provide a referee condition for the evaluation of the solderability of terminations (including leads up to 0.125 inch in diameter) that will be assembled using tin lead eutectic solder.	This evaluation is made on the basis of the ability of these terminations to be wetted and to produce a suitable fillet when coated by tin lead eutectic solder. These procedures will test whether the packaging materials and processes used during the manufacturing operations process produce a component that can be successfully soldered to the next level assembly using tin lead eutectic solder. A preconditioning test is included in this test method, which degrades the termination finish to provide a guard band against marginal finish.			
Repetitive surges	Devices are submitted to rated lpp for 50 surges.	This test is intended to verify robustness of device submitted to rated Ipp (as per data sheet) = exploration of reverse characteristic at a calibrated current value followed by the measure of voltage clamping value. Failure mode expected is short circuit of the device due to hot spot creation into silicon bulk at device periphery where the electrical field gradient is the most important. Physical analysis must be done to verify consistency of the failure mode and discriminate from extrinsic causes related to process escapes.			